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# ±200V Common-Mode Voltage DIFFERENCE AMPLIFIER

### **FEATURES**

- HIGH COMMON-MODE VOLTAGE: +75V at  $V_s = +5V$  $\pm 200V$  at  $V_s = \pm 15V$
- FIXED DIFFERENTIAL GAIN = 1V/V
- LOW QUIESCENT CURRENT: 260μA
- WIDE SUPPLY RANGE: Single Supply: 2.7V to 36V Dual Supplies: ±1.35V to ±18V
- LOW GAIN ERROR: 0.075% max
- LOW NONLINEARITY: 0.002% max
- HIGH CMR: 86dB
- SO-8 PACKAGE

### **APPLICATIONS**

- CURRENT SHUNT MEASUREMENTS
- DIFFERENTIAL SENSOR AMPLIFIERS
- LINE RECEIVERS
- BATTERY POWERED SYSTEMS
- AUTOMOTIVE INSTRUMENTATION
- STACKED CELL MONITORS

## DESCRIPTION

The INA148 is a precision, low-power, unity-gain difference amplifier with a high common-mode input voltage range. It consists of a monolithic precision bipolar op amp with a thin-film resistor network.

The on-chip resistors are laser trimmed for an accurate 1V/V differential gain and high common-mode rejection. Excellent temperature tracking of the resistor network maintains high gain accuracy and common-mode rejection over temperature. The INA148 will operate on single or dual supplies.

The INA148 is available in a small SO-8 surfacemount package and it is specified for the  $-40^{\circ}$ C to +85°C extended industrial temperature range.



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# SPECIFICATIONS: V<sub>S</sub> = $\pm$ 5V to $\pm$ 15V Dual Supplies

At  $T_A$  = +25°C,  $R_L$  = 10k $\Omega$  connected to ground and Ref pin connected to ground, unless otherwise noted.

	CONDITIONS					
	CONDITIONS	MIN TYP MA			UNITS	
	RTI(1)(2)					
Vos	$V_S = \pm 15 V$ , $V_{CM} = 0 V$		±1	±5	mV	
	$V_{S} = \pm 5V, V_{CM} = 0V$		±1	±5	mV	
V <sub>OS</sub> /∆T	At $T_A = -40^{\circ}C$ to $+85^{\circ}C$		±10		μV°C	
PSRR	$V_{S}$ = $\pm 1.35V$ to $\pm 18V,~V_{CM}$ = 0V		±50	±400	μ٧/٧	
INPUT VOLTAGE RANGE Common-Mode Voltage Range V <sub>CM</sub>		-200		+200	V	
	$V_{S} = \pm 5V, (V_{IN}^{+}) - (V_{IN}^{-}) = 0V$	-100		+80	V	
CMRR		70	86		dB	
	$V_{S}=\pm5V,~V_{CM}=-100V$ to +80V, $R_{S}=0\Omega$	70	86		dB	
			2		MΩ	
			1		MΩ	
	RTI <sup>(1)(3)</sup>					
NOISE Voltage Noise, f = 0.1Hz to 10Hz e <sub>n</sub>			17		μVp-p	
			880		nV/√Hz	
			1		V/V	
	$V_0 = (V-) + 0.5$ to $(V+) - 1.5$		±0.01	±0.075	%	
			±3	±10	ppm/°C	
			±0.001	±0.002	% of FSR	
	$V_{S} = \pm 5V, V_{O} = (V-) + 0.5$ to $(V+) - 1.5$		±0.001		% of FSR	
			100		kHz	
			1		V/µs	
	$V_S = \pm 15V$ , 10V Step		21		μs	
					μs	
					μs	
0.01% Overload Recovery					μs	
	50% Input Overload		24		μs	
	-	. ,		· · /	V	
	$R_L = 10k\Omega$	(V–) + 0.5		(V+) – 1.5	V	
I <sub>O</sub>			140		- A	
					mA nF	
			10		IIF	
		±1.35	1000		V	
	$v_{IN} = 0, I_O = 0$		±260	±300	μΑ	
					°C	
				I I	°C ℃	
Storage Thermal Resistance $\theta_{IA}$ SO-8 Surface Mount		-55	150	120	°C/W	
	/ <sub>OS</sub> /ΔT PSRR V <sub>CM</sub> CMRR	$\begin{array}{c c} V_{S} \pm \pm 5V, \ V_{CM} = 0V \\ At \ T_{A} = -40^{\circ}C \ to \ +85^{\circ}C \\ V_{S} = \pm 1.35V \ to \ \pm 18V, \ V_{CM} = 0V \\ \hline \\ V_{CM} & V_{S} = \pm 15V, \ (V_{h}^{*}) - (V_{lN}^{*}) = 0V \\ V_{S} = \pm 5V, \ V_{CM} = -200V \ to \ \pm 200V, \ R_{S} = 0\Omega \\ \hline \\ $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

NOTES: (1) Overall difference amplifier configuration. Referred to input pins  $(V_{IN}^+ \text{ and } V_{IN}^-)$ , gain = 1V/V (2) Input offset voltage specification includes effects of amplifier's input bias and offset currents. (3) Includes effects of input current noise and thermal noise contribution of resistor network.



# SPECIFICATIONS: $V_S = +5V$ Single Supply

At T<sub>A</sub> = +25°C, R<sub>L</sub> = 10k $\Omega$  connected to V<sub>S</sub>/2 and Ref pin connected to V<sub>S</sub>/2, unless otherwise noted.

			INA148UA				
PARAMETER		CONDITIONS	MIN TYP		MAX	UNITS	
OFFSET VOLTAGE (V <sub>0</sub> )		RTI(1)(2)					
Input Offset Voltage	Vos	$V_{CM} = V_{s}/2$		±1	±5	mV	
Drift $\Delta V_{OS}/\Delta T$		At $T_A = -40^{\circ}$ C to $+85^{\circ}$ C		±10		μV°C	
vs Power Supply	66 A			±50	±400	μV/V	
INPUT VOLTAGE RANGE							
Common-Mode Voltage Range V <sub>CM</sub>		$(V_{IN}^+) - (V_{IN}^-) = 0V, V_{REF} = 0.25V$	-4		+75	V	
gg-	- Civi	$(V_{IN}) - (V_{IN}) = 0V, V_{REF} = V_{s}/2$	-47.5		+32.5	V	
		$V_{CM} = -47.5V$ to +32.5V, $R_{S} = 0\Omega$	70	86		dB	
INPUT IMPEDANCE							
Differential				2		MΩ	
Common Mode				1		MΩ	
NOISE		RTI(1)(3)					
Voltage Noise, $f = 0.1Hz$ to 10Hz	en			17		μVp-p	
Voltage Noise Density, $f = 1 \text{ kHz}$	on			880		nV/√Hz	
GAIN							
Initial <sup>(1)</sup>				1		V/V	
		$V_0 = +0.5V$ to $+3.5V$		±0.01	±0.075	%	
vs Temperature		10.01 10.01		±3	±10	ppm/°C	
Nonlinearity		$V_0 = +0.5V$ to $+3.5V$		±0.001		% of FSR	
FREQUENCY RESPONSE							
Small Signal Bandwidth				100		kHz	
Slew Rate				1		V/µs	
Settling Time: 0.1%		V <sub>S</sub> = +5V, 3V Step		21		μs	
0.01%		$V_{S} = +5V$ , 3V Step		25		μs	
Overload Recovery		50% Input Overload		13		μs	
OUTPUT (V <sub>o</sub> )							
Voltage Output		$R_{L} = 100 k\Omega$	(V–) + 0.25		(V+) − 1	V	
Voltage Output		$R_1 = 10k\Omega$	(V-) + 0.5		(V+) – 1.5	v	
Output Current	Ι <sub>ο</sub>		(1) / 0.0		(11) 110		
Short-Circiuit Current	.0	Continuous to Common		±8		mA	
Capacitive Load		Stable Operation		10		nF	
POWER SUPPLY		-					
Operating Range, Single Supply			+2.7		+36	V	
Quiescent Current		$V_{IN} = 0, I_{O} = 0$		260	300	μÂ	
		II				P	
Specified			-40		85	°C	
Operating			-40 -55		05 125	°C ℃	
Storage			-55 -55		125	℃	
Thermal Resistance	$\theta_{JA}$	SO-8 Surface Mount		150	120	°C/W	

NOTES: (1) Overall difference amplifier configuration. Referred to input pins  $(V_{iN}^{+} \text{ and } V_{iN}^{-})$ , gain = 1V/V (2) Input offset voltage specification includes effects of amplifier's input bias and offset currents. (3) Includes effects of input current noise and thermal noise contribution of resistor network.



#### **PIN CONFIGURATION**



#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage, V+ to V	
Signal Input Terminals, Continuous	±200V
Peak (0.1s)	±500V
Output Short Circuit to GND Duration	Continuous
Operating Temperature	55°C to +125°C
Storage Temperature	55°C to +125°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

NOTE: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

#### PACKAGE/ORDERING INFORMATION

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER <sup>(1)</sup>	TRANSPORT MEDIA
INA148UA	SO-8	182	–40°C to +85°C	INA148UA	INA148UA	Rails
"	"	"	"	"	INA148UA/2K5	Tape and Reel

NOTE: (1) Models with a slash (/) are available only in Tape and Reel in the quantities indicated (e.g., /2K5 indicates 2500 devices per reel). Ordering 2500 pieces of "INA148UA/2K5" will get a single 2500-piece Tape and Reel.

The information provided herein is believed to be reliable; however, BURR-BROWN assumes no responsibility for inaccuracies or omissions. BURR-BROWN assumes





## ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### **TYPICAL PERFORMANCE CURVES**

At T<sub>A</sub> = +25°C, V<sub>S</sub> = ±15V, R<sub>L</sub> = 10k $\Omega$  to common, and V<sub>REF</sub> = 0V, unless otherwise noted.





POWER SUPPLY REJECTION vs FREQUENCY 110 PSR+ 100 = ±18V) ίV 90 Power Supply Rejection (dB) 4111 PSR+ 80  $(V_{S} = \pm 1.35V)$ PSR-70  $(V_{S} = \pm 18V)$ 60 PSR 50 = +1.35V(Vs 40 30 20 10 1 10 100 1k 10k 100K Frequency (Hz)





QUIESCENT CURRENT vs TEMPERATURE 290 280 270 260 250 240  $V_{s} = \pm 15V$  $V_{s} = \pm 2.5V$ 



**INA148** 



l<sub>Q</sub> (μA)

## **TYPICAL PERFORMANCE CURVES (Cont.)**

At T<sub>A</sub> = +25°C, V<sub>S</sub> = ±15V, R<sub>L</sub> = 10k $\Omega$  to common, and V<sub>REF</sub> = 0V, unless otherwise noted.





OUTPUT VOLTAGE SWING vs RL  $R_L = 100k\Omega$   $R_L = 1k\Omega$   $R_L = 10k\Omega$   $R_L = 10k\Omega$  $R_L = 10k\Omega$ 

1ms/div











### TYPICAL PERFORMANCE CURVES (Cont.)

At T\_A = +25°C, V\_S =  $\pm 15$ V, R\_L = 10k $\Omega$  to common, and V\_{REF} = 0V, unless otherwise noted.









OFFSET VOLTAGE DRIFT PRODUCTION DISTRIBUTION 20  $V_{S} = \pm 2.5 V$ Percent of Amplifiers (%) 15 10 5 0 -30.0 -24.0 -18.0 -12.0 9.0 6.0 12.0 18.0 24.0 30.0 0.0

Offset Voltage Drift, RTI (µV/°C)





### TYPICAL PERFORMANCE CURVES (Cont.)

At  $T_A = +25^{\circ}C$ ,  $V_S = \pm 15V$ ,  $R_L = 10k\Omega$  to common, and  $V_{REF} = 0V$ , unless otherwise noted.





### **APPLICATION INFORMATION**

The INA148 is a unity gain difference amplifier with a high common-mode input voltage range. A basic diagram of the circuit and pin connections is shown in Figure 1.

To achieve its high common-mode voltage range, the INA148 features a precision laser-trimmed thin-film resistor network with a 20:1 input voltage divider ratio. High input voltages are thereby reduced in amplitude, allowing the internal op amp to "see" input voltages that are within its linear operating range. A "Tee" network in the op amp feedback network places the amplifier in a gain of 20V/V, thus restoring the circuit's overall gain to unity (1V/V).

External voltages can be summed into the amplifier's output by using the Ref pin, making the differential amplifier a highly versatile design tool. Voltages on the Ref pin will also influence the INA148's common-mode voltage range.

In accordance with good engineering practice for linear integrated circuits, the INA148's power-supply bypass capacitors should be connected as close to pins 4 and 7 as practicable. Ceramic or tantalum types are recommended for use as bypass capacitors.

The input impedances are unusually high for a difference amplifier and this should be considered when routing input signal traces on a PC board. Avoid placing digital signal traces near the difference amplifier's input traces to minimize noise pickup.

#### **OPERATING VOLTAGE**

The INA148 is specified for  $\pm 15V$  and  $\pm 5V$  dual supplies and  $\pm 5V$  single supplies. The INA148 can be operated with single or dual supplies with excellent performance.

The INA148 is fully characterized for supply voltages from  $\pm 1.35$ V to  $\pm 18$ V and over temperatures of -55°C to +125 °C. Parameters that vary significantly with operating voltage, load conditions, or temperature are shown in the Typical Performance Curves section.



FIGURE 1. Basic Circuit Connections.



#### THE GAIN EQUATION

An internal on-chip resistor network sets the overall differential gain of the INA148 to precisely 1V/V. It's output is accordance with the equation:

$$V_{OUT} = (V_{IN}^{+} - V_{IN}^{-}) + V_{REF}$$
(1)

#### **COMMON-MODE RANGE**

The 20:1 input resistor ratio of the INA148 provides an input common-mode range that extends well beyond its power supply rails.

The exact input voltage range depends on the amplifier's power-supply voltage and the voltage applied to the Ref terminal (pin 1). Typical input voltage ranges at different power supply voltages can be found in the applications circuits section.

#### **OFFSET TRIM**

The INA148 is laser-trimmed for low offset voltage and drift. Most applications will require no external offset adjustment.

Since a voltage applied to the reference (Ref) pin (pin 1) will be summed directly into the amplifier's output signal, this technique can be used to null the amplifier's input offset voltage. Figure 2 shows an optional circuit for trimming the offset voltage.

To maintain high common-mode rejection (CMR), the source impedance of any signal applied to the Ref terminal should be very low ( $\leq 5\Omega$ ).

A source impedance of only  $10\Omega$  at the Ref pin will reduce the INA148's CMR to approximately 74dB. High CMR can be restored if a resistor is added in series with the amplifier's positive input terminal (pin 3). This resistor should be 19 times the source impedance that drives the Ref pin. For example, if the Ref pin sees a source impedance of  $10\Omega$ , a resistor of  $190\Omega$  should be added in series with pin 3.



FIGURE 2. Optional Offset Trim Voltage.



FIGURE 3. Preferred Offset Trim Circuit.



Preferably, the offset trim voltage applied to the Ref pin should be buffered with an amp such as an OPA237 (see Figure 3). In this case, the op amp output impedance is low enough that no external resistor is needed to maintain the INA148's excellent CMR.

#### **INPUT IMPEDANCE**

The input resistor network determines the impedance of each of the INA148's inputs. It is approximately  $1M\Omega$ . Unlike an instrumentation amplifier, signal source impedances at the two input terminals must be nearly equal to maintain good common-mode rejection.

A mismatch between the two inputs' source impedances will cause a differential amplifier's common-mode rejection to be degraded. With a source impedance imbalance of only  $500\Omega$ , CMR can fall to approximately 66dB.

Figure 4 shows a common application—measuring power supply current through a shunt resistor ( $R_S$ ). A shunt resistor creates an unbalanced source resistance condition that can degrade a differential amplifier's common mode rejection.

Unless the shunt resistor is less than approximately  $100\Omega$ , an additional equal compensating resistor ( $R_C$ ) is recommended to maintain input balance and high CMR.

Source impedances (or shunts) greater than  $5k\Omega$  are not recommended, even if they are "perfectly" compensated. This is because the internal resistor network is laser-trimmed for accurate voltage divider ratios, but not necessarily to absolute values. Input resistors are shown as  $1M\Omega$ , however, this is only their nominal value.

In practice, the input resistors' absolute values may vary by as much as 30 percent. The two input resistors match to about 5 percent, so adding compensating resistors greater than  $5k\Omega$  can cause a serious mismatch in the resulting resistor network voltage divider ratios, thus degrading CMR.

Attempts to extend the INA148 input voltage range by adding external resistors is not recommended for the reasons just described in the last paragraph. CMR will suffer a serious degradation unless the resistors are carefully trimmed for CMR and gain. This is an iterative adjustment and can be tedious and time consuming.



FIGURE 4. Shunt-Resistor Current Measurement Circuit.



FIGURE 5. AC-Coupled Difference Amplifier.





FIGURE 6. Quasi-AC-Coupled Differential Amplifier.



FIGURE 7. Single-Supply Differential Amplifier.



FIGURE 8. Battery Monitor Circuit.



FIGURE 9. 50mV Current Shunt Amplifier with ±200V Common-Mode Voltage Range.

